

What is claimed is:

1. An in-plane switching mode LCD device, comprising:
 - a substrate;
 - a plurality of common electrodes at fixed intervals in one direction on the substrate;
 - an insulating layer on the substrate including the plurality of common electrodes;
 - a plurality of pixel electrodes at fixed intervals on the insulating layer between the plurality of common electrodes; and
 - a dummy common electrode on the insulating layer at one side of the plurality of pixel electrodes, the dummy common electrode electrically connected to an outermost common electrode among the plurality of common electrodes.
2. The in-plane switching mode LCD device of claim 1, wherein the plurality of pixel electrodes are formed of the same material as the dummy common electrode.
3. The in-plane switching mode LCD device of claim 1, wherein the insulating layer includes a gate insulating layer and a passivation layer.
4. The in-plane switching mode LCD device of claim 3, further comprising a plurality of data lines on the gate insulating layer substantially perpendicular to gate lines on the substrate.
5. The in-plane switching mode LCD device of claim 1, further comprising:
 - thin film transistors at crossing points of data and gate lines; and
 - a common line on a same surface as the gate lines, the common line formed of the same material as the plurality of common electrodes.
6. An in-plane switching mode LCD device, comprising:
 - a substrate;

gate and common electrodes on the substrate;
a gate insulating layer on the substrate;
a semiconductor layer on the gate insulating layer above the gate electrode;
a data line having source and drain electrodes above both sides of the semiconductor layer;
a passivation layer on the substrate including the data line;
a pixel electrode on the passivation layer, the pixel electrode connected to the drain electrode via a first contact hole; and
a dummy common electrode on the passivation layer at one side of the pixel electrode, the dummy common electrode connected to the common electrode via a second contact hole.

7. The in-plane switching mode LCD device of claim 6, wherein the pixel electrode is formed of the same material as the dummy common electrode.

8. A method for manufacturing an in-plane switching mode LCD device, comprising:

forming a gate line having a gate electrode and a common line having a common electrode on a substrate;

forming a gate insulating layer on the substrate;

forming a data line on the gate insulating layer substantially perpendicular to the gate line, the data line having source and drain electrodes;

forming a passivation layer on the substrate including the data line;

forming a pixel electrode on the passivation layer, the pixel electrode connected to the drain electrode; and

forming a dummy common electrode on the passivation layer, the dummy common electrode connected to an outermost common electrode.

9. The method of claim 8, further comprising sequentially forming an active layer and an ohmic layer on the substrate after forming the gate insulating layer.

10. The method of claim 9, wherein the active layer and ohmic layer are selectively removed.
11. The method of claim 8, wherein further comprising forming a contact hole in the passivation layer over the outermost common electrode.
12. The method of claim 8, wherein the pixel electrode is formed of the same material as the dummy common electrode.